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Molecular dynamics study of radiation damage and microstructure evolution of zigzag single-walled carbon nanotubes under carbon ion incidence

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ABSTRACT

The radiation damage and microstructure evolution of different zigzag single-walled carbon nanotubes (SWCNTs) were investigated under incident carbon ion by molecular dynamics (MD) simulations. The radiation damage of SWCNTs under incident carbon ion with energy ranging from 25 eV to 1 keV at 300 K showed many differences at different incident sites, and the defect production increased to the maximum value with the increase in incident ion energy, and slightly decreased but stayed fairly stable within the majority of the energy range. The maximum damage of SWCNTs appeared when the incident ion energy reached 200 eV and the level of damage was directly proportional to incident ion fluence. The radiation damage was also studied at 100 K and 700 K and the defect production decreased distinctly with rising temperature because radiation-induced defects would anneal and recombine by saturating dangling bonds and reconstructing carbon network at the higher temperature. Furthermore, the stability of a large-diameter tube surpassed that of a thin one under the same radiation environments.

1. Introduction

Single-walled carbon nanotubes (SWCNTs), as an emerging quasi-one-dimensional material with extraordinary mechanical and electrical properties, have extensive applications such as sensors, thin-film transistors [1,2], and high-performance composites [3]. Carbon nanotube-based tape offered an excellent synthetic option as a dry conductive reversible adhesive in microelectronics, robotics and aerospace application [4], and carbon nanotube matrices combined with quantum dot might be used in space photovoltaic devices [5]. These CNTs-based aerospace devices may be exposed to harsh radiation environments, and they are continuously bombarded by energetic particles under these severe conditions. Unfortunately, the radiation-induced structural changes in CNTs significantly affect their physical, electrical and morphological properties [6–10]. Furthermore, the structure and properties of CNTs can be tailored and modified with various forms of ionizing radiation, including high-energy gamma rays, electrons and ions [11]. Vacancies and interstitials created by displacement cascades under abundant high-energy charged particles in SWCNTs would eventually form defect clusters (voids, interstitial clusters and non-hexagonal rings) due to the accumulation effects.

Previous works on the ion beam interacting with CNTs focused on cutting and doping CNTs. For example, energetic focused Ga^+ ions beam was applied to thin, slice, wield and change the structure and composition of CNTs at precise positions along the nanotube axis [12]. However, the microstructure evolution of defects generated in carbon nanotubes under focused ion irradiation was difficult to obtain from experiments. In the meantime, the prediction of structural configuration was allowed through computational and theoretical simulations after exposure to an energetic particle beam. M. Khazaei et al. adopted *ab initio* molecular dynamics simulations to clarify Cs^+ insertion and adsorption processes which is shot toward the cap and stem of two kinds of armchair nanotubes by considering the impact angle, impact position and the kinetic energy of dopant [13]. T. Kato et al. illustrated the damage-free and position-selective encapsulation of Cs into SWCNTs, and the minimum energy threshold of Cs-ion doping matched well with the value obtained by *ab initio* simulation [14]. Molecular dynamics (MD) simulation was employed to study the improved inter-tube coupling [15], and the structural and formation yields of atomic-scale defects [16] in SWCNTs bundles through C and Ar ion irradiation by O'Brien and E. Salonen, respectively. S. K. Pregler et al. also used MD simulation to investigate the

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surface structure and mechanical properties of polystyrene-carbon nanotube composites under Ar ion irradiation [17]. Furthermore, the stability of armchair SWCNTs with a small tube diameter under ion irradiation with the energy range of 25 eV–1 keV was investigated by Z. Xu in detail [18]. E.C. Neyts et al. indicated that ion bombardment in the lower energy window of 10–25 eV actually allowed radiation-induced defects to be healed resulting in an enhanced nucleation of the carbon nanotube cap through combining experiment and MD simulation [19,20].

However, it should be noted that the tube diameter, chirality, temperature and incident ion fluences are the critical influencing factors of the radiation damage and microstructure evolution of carbon nanotubes, and that detailed local damage information at different sites of SWCNTs could not be determined explicitly because the impact positions are randomly selected within the minimum irreducible area in the primitive cell of carbon nanotubes. Therefore, it is necessary to explore more details of the above critical factors.

In the present work, molecular dynamics simulations were used to explore the radiation damage and microstructure evolution of SWCNTs under various irradiation conditions. Incident carbon ion was chosen since it introduced no impurity into the system and enabled efficient momentum transfer due to the match between the mass of the impinging ion and target atoms. We classified the incident sites of SWCNTs into three types to investigate the defect production mechanism and evolution of zigzag carbon nanotubes under ion irradiation. We studied the influence of ion irradiation on different sites of SWCNTs under the incident ion fluences ranging from 2×10^{13} ions/cm^2 to 2×10^{14} ions/cm^2. The incident ion fluence range was comparable to that in the aerospace environment [21]. As a critical factor that affected the evolution of radiation-induced defects, the influence of temperature on SWCNTs was investigated as well. Moreover, the role of the tube diameter was also discussed in the stability of SWCNTs under irradiation.

2. Simulation methods

The public-domain parallelized program LAMMPS code [22] distributed by Sandia National Laboratories was used to perform all simulations in the study. The interactions between carbon atoms in SWCNTs were described by the adaptive intermolecular reactive empirical bond order (AIREBO) potential [23], which was appropriate to study the reactivity in molecular condensed-phase hydrocarbon systems. Tersoff-like [24] potential, which was smoothly connected with the Ziegler–Biersack–Littmark (ZBL) universal repulsive potential [25] at short interatomic distances using a Fermi function, was employed to simulate realistically close collisions between incident and target atoms. This type of potential has been successfully applied to simulate the irradiation and implantation of carbon nanomaterials [26,27]. The high-end cutoff radius was optimized to the value 2.46 Å and the Tersoff potential parameter λ_3 was set equal to λ_2 as in Ref. [27]. As the incident ion energies were low and the nuclear stopping governed the collisional phase, electronic stopping was not taken into consideration.

The chiral (n, 0) zigzag SWCNTs was considered in our simulations. We selected (7, 0), (13, 0), (19, 0) and (25, 0) zigzag SWCNTs composed of 560, 1040, 1520 and 2000 atoms for the model calculations. The lengths for these tubes were all about 85.20 Å and the diameter ranged from 0.4 nm to 2.0 nm. The simulated diameter corresponded to the actual diameter of nanotubes synthesized in the experiment [28]. As shown in Fig. 1, the selected incident ion was firstly placed 3 nm above the nanotube surface and had negligible interactions with the target atoms. For each tube, a periodic boundary condition along the tube axis was used and non-

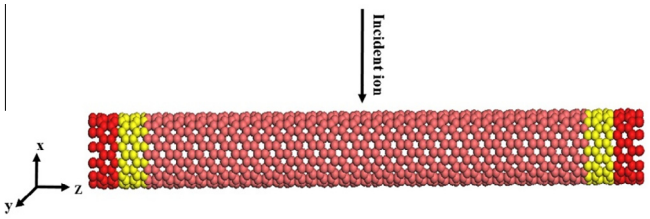

Fig. 1. Side view of the simulation setup used. The incident ion was initially above the surface of SWCNTs. In this model, the yellow atoms close to both ends acted as a thermostat region to maintain a constant temperature; the red atoms were kept fixed during the simulation; and the central region of the thermostat was used to simulate the collision cascades process. (For interpretation of the references to color in this figure legend, the reader is referred to the web version of this article.)

periodic conditions were adopted in the other two dimensions. An initial relaxation phase of 10 ps with a fixed time step of 0.1 fs was applied to equilibrate the system at the NVT ensemble (300 K). A time step of 0.05 fs was used to simulate the ion-SWCNTs interaction during the collision cascades phase. The simulations were carried out for 25 ps. Atoms in the thermostat region were kept at a constant temperature of 300 K through the Nosé-Hoover heat bath, using a coupling constant of 1 ps, so that the excess kinetic energy introduced by the incident ion would be dissipated as that in the experimental situations, and the atoms at both ends of SWCNTs were kept fixed in order to prevent CNTs from being displaced by the transfer of momentum.

The collision process between an energetic ion and SWCNTs was investigated by assigning the energy of incident carbon ion ranging from 25 eV to 1 keV. For each type of SWCNTs, each incident ion energy, each temperature (100 K, 300 K and 700 K) and each ion fluence (2×10^{13}, 6×10^{13}, 1×10^{14} and 2×10^{14}/cm^2), five independent runs were carried out at different sites of SWCNTs and the final results were averaged. The evolution of the system was monitored and then the structural configuration and stability of SWCNTs were analyzed.

3. Results and discussion

In our simulation, we identified the types and abundance of defects which appeared in SWCNTs surface under ion radiation with energies ranging from 25 eV to 1 keV in different models, including a single vacancy, divacancy, adatom, and non-hexagonal rings. To describe the irradiation effects of an incident ion to SWCNTs, we calculated two kinds of defect production quantitatively: the coordination defect number (CDN) and sputtering yield (Y). The CDN is defined as the number of target atoms that have other than three nearest neighbors or bonds, and the Y is defined as the number of target atoms that are sputtered from the SWCNTs surface per incident ion. These two kinds of defect production, to some extent, could reflect the structural configuration and stability of SWCNTs.

3.1. Influence of different incident sites on SWCNTs

The initial positions of an incident ions are randomly distributed on the wall of SWCNTs in actual experiment. However, in our simulation we discover that the defect production of different impinging positions has remarkable differences, therefore it may introduce significant statistical errors. In order to clarify the radiation damage mechanism of SWCNTs at different ion incident sites, we classify the impinging sites of SWCNTs into three specific types in our study, as shown in Fig. 2. The first type is the C atom (Site 1), where an incident ion vertically impacts the carbon atom